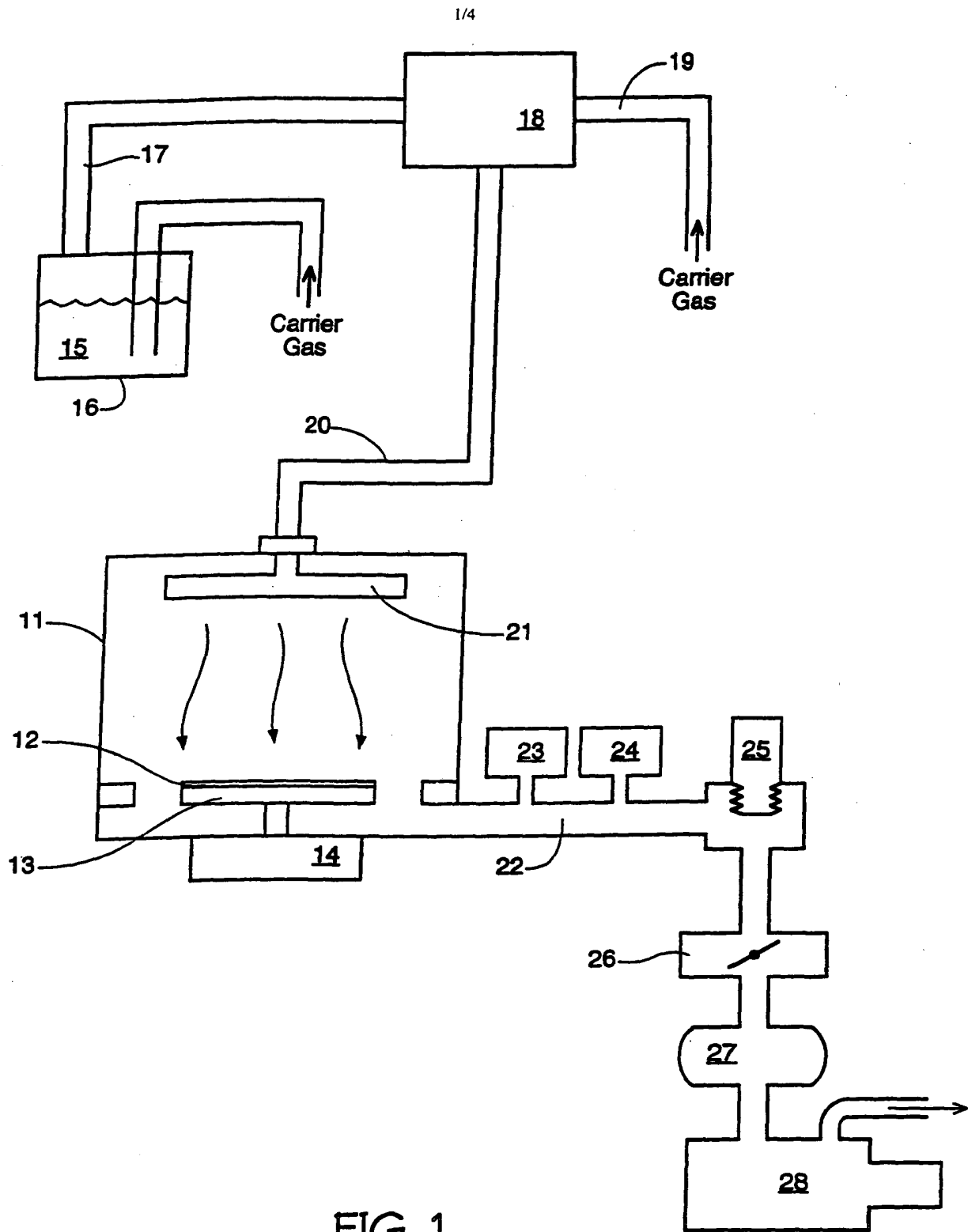


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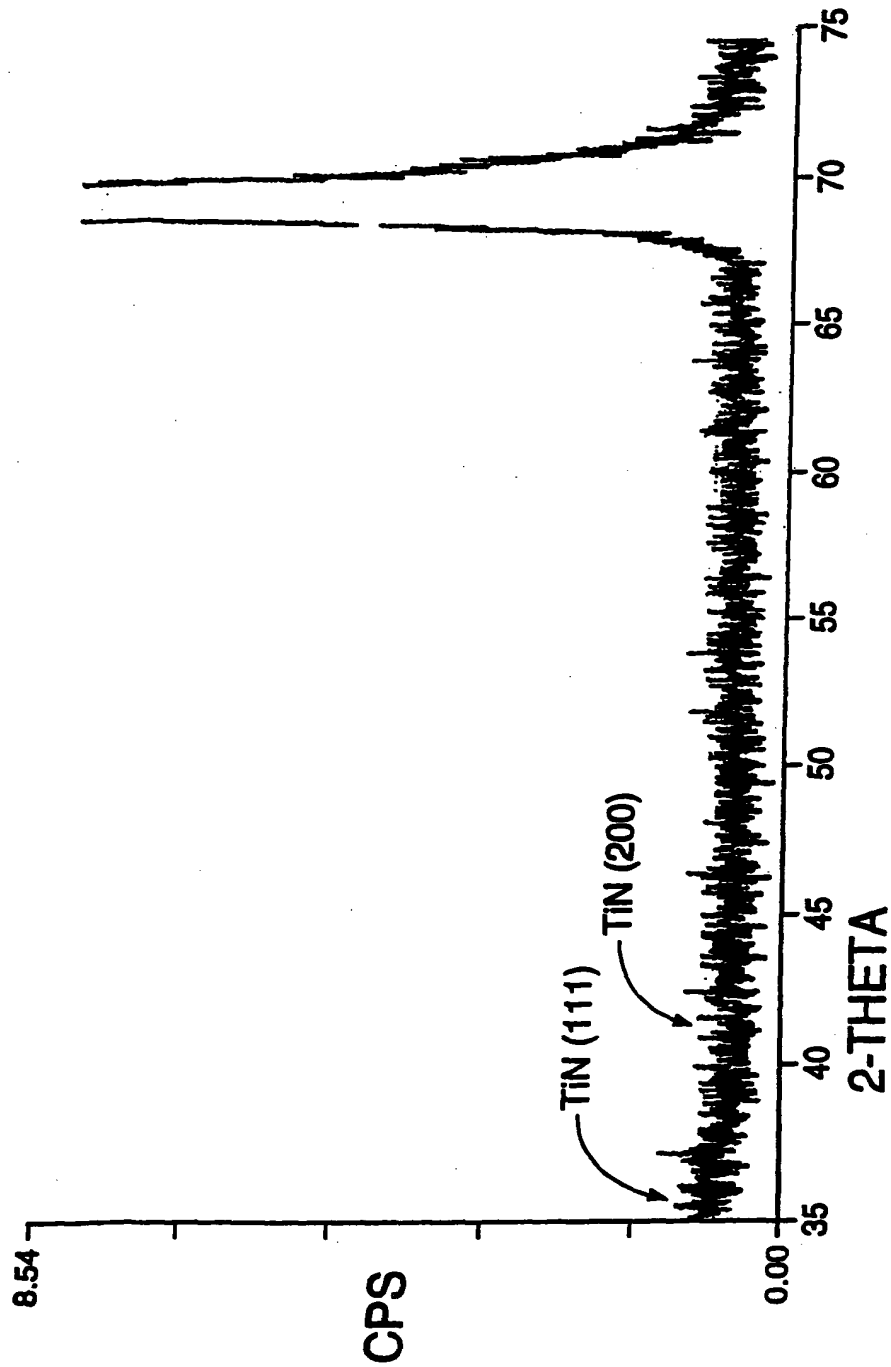


FIG. 2

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FIG. 3

FIG. 3

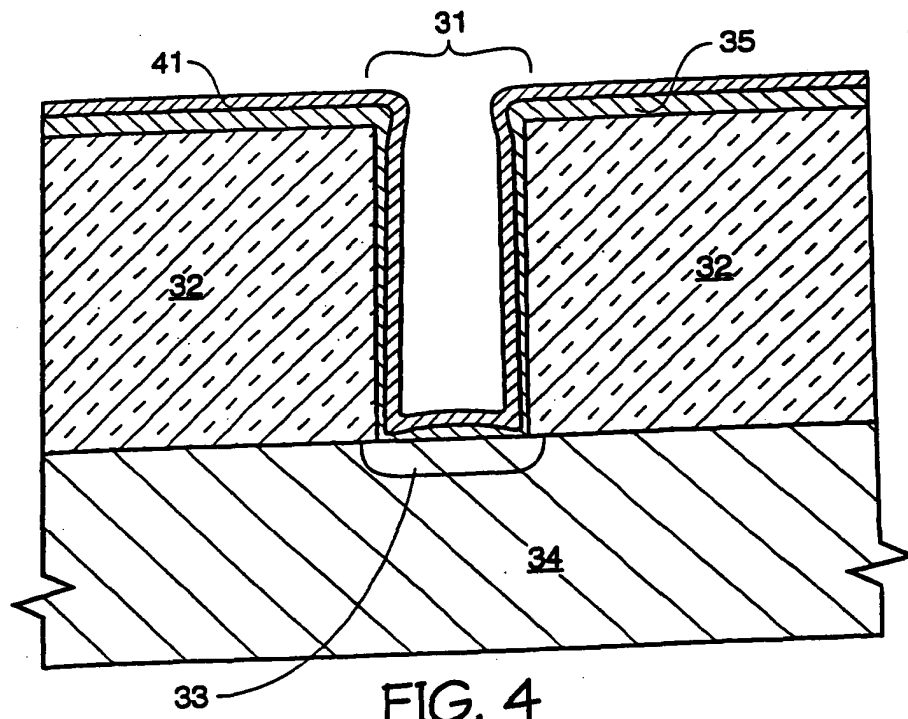


FIG. 4

